EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S100	43	S99 and heat near2 treat$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 15:31
L1	673	(kozo near2 nakamura or toshiaki near2 saishoji or hirotaka near2 nakajima or masashi near2 nishimura or toshirou near2 kotooka near2 yoshiyuki near2 shimanuki).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 15:31
L2	45	L1 and heat near2 treat$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 15:49
L4	7	L1 and anneal$6 and temperature near3 rate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 15:52
L3	13	L1 and heat near2 treat$6 and temperature near3 rate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 15:52
L5	1687	anneal$6 and temperature near3 rate and (si or silicon) near5 (single near2 crystal or monocrystal$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 16:01
L8	447	(anneal$6 or heat near2 treat$4) same temperature near3 rate same (si or silicon) and (si or silicon) near5 (single near2 crystal or monocrystal$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 16:02
L7	201	(anneal$6 or heat near2 treat$4) same temperature near3 rate same (si or silicon) near5 (single near2 crystal or monocrystal$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 16:02
L6	693	(anneal$6 or heat near2 treat$4) same temperature near3 rate and (si or silicon) near5 (single near2 crystal or monocrystal$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 16:02

L10	21	(anneal$6 or heat near2 treat$4) same temperature near3 rate near10 less same (si or silicon) and (si or silicon) near5 (single near2 crystal or monocrystal$5) and @py<"2003"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 16:03
L9	223	(anneal$6 or heat near2 treat$4) same temperature near3 rate same (si or silicon) and (si or silicon) near5 (single near2 crystal or monocrystal$5) and @py<"2003"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 16:03
S71	17	heat near2 treat$4 near10 temperature near5 start$5 same (si or silicon) near5 (single near2 crystal$5 or wafer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 16:05
S52	24	(anneal$ or heat$3 near2 treat$4) same (Si or silicon) near4 wafer same rate near3 slow$3 same temperature	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 16:05
S48	44	(anneal$ or heat$3 near2 treat$4 or rta or rtp or ptp) same (Si or silicon) near4 wafer same (low or slow or reduc$4) near2 rate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 16:05
L13	22	heat near2 treat$4 near10 temperature near5 start$5 same (si or silicon) near5 (single near2 crystal$5 or wafer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 16:05
L12	68	(anneal$ or heat$3 near2 treat$4 or rta or rtp or ptp) same (Si or silicon) near4 wafer same (low or slow or reduc$4) near2 rate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 16:05
L11	44	(anneal$ or heat$3 near2 treat$4) same (Si or silicon) near4 wafer same rate near3 slow$3 same temperature	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 16:05
L15	99	14 and (anneal$5 or heat near2 treat$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 16:06
L14	122	117/3.ccls. and (si or silicon) near5 (single near2 crystal$5 or monocrystal$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 16:06

S10 1	138	(anneal$ or heat$3 near2 treat$4 or rta or rtp or ptp) same (Si or silicon) near4 wafer same (heat$4 or ramp$4) near2 rate same temperature	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 16:08
L16	145	(anneal$ or heat$3 near2 treat$4 or rta or rtp or ptp) same (Si or silicon) near4 wafer same (heat$4 or ramp$4) near2 rate same temperature	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 18:31
L18	6	("4437922" "4944834" "6036776").pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 18:32
L17	6	("4437922" "4944834" "6039776").pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/09 18:32